

EPO-TEK® H20E-FC

Technical Data Sheet For Reference Only Electrically Conductive Epoxy

Date: September 2017

Rev: IV
No. of Components: Two
Mix Ratio by Weight: 1:1

Specific Gravity: Part A: 3.80 Part B: 2.51

Pot Life: 20 Hours

Shelf Life- Bulk: One year at room temperature

Recommended Cure: 140°C / 10 Minutes

Minimum Alternative Cure(s):

May not achieve performance properties listed below

140°C / 35 Seconds 120°C / 15 Minutes 80°C / 45 Minutes

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages

<u>Product Description:</u> EPO-TEK® H20E-FC is a two-component, electrically conductive, snap curing epoxy for photovoltaic thin film module stringing, semiconductor packaging and PCB circuit assembly.

<u>Typical Properties:</u> Cure condition: 140°C / 10 Minutes Different batches, conditions & applications yield differing results.

Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:		
* Color (before cure):	Part A: Silver	Part B: Silver
* Consistency:	Smooth thixotropic paste	
* Viscosity (23°C) @ 50 rpm:	1,000 - 5,000	
Thixotropic Index:	4.6	
* Glass Transition Temp:	≥ 70	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)
Coefficient of Thermal Expansion (CTE):		
Below Tg	: 53	x 10 ⁻⁶ in/in°C
Above Tg	: 233	x 10 ⁻⁶ in/in°C
Shore D Hardness:	55	
Lap Shear @ 23°C:	> 2,000	psi
Die Shear @ 23°C:	≥ 10	Kg 3,556 psi
Degradation Temp:	392	°C
Weight Loss:		
@ 200°C	: 0.73	%
@ 250°C	1.67	%
@ 300°C	2.37	%
Suggested Operating Temperature:	< 300	°C (Intermittent)
Storage Modulus:	927,509	psi
* Particle Size:	≤ 45	microns

ELECTRICAL AND THERMAL PROPERTIES:		
Thermal Conductivity:	2.6	W/mK
* Volume Resistivity @ 23°C:	≤ 0.0004	Ohm-cm



EPO-TEK® H20E-FC

Technical Data Sheet
For Reference Only
Electrically Conductive Epoxy

EPO-TEK® H20E-FC Advantages & Suggested Application Notes:

- It is a snap cure version of EPO-TEK® H20E, designed for snap cure at 140°C and <15 minute cure at 120°C.
- Strengths include dispensable rheology and a long pot life.
- Suggested Applications:
 - Semiconductor: die-attaching IC's onto Cu plated lead-frame yielding semiconductor plastic package formats.
 - PCB: solder replacement adhesive, electrical bridge of Au, Ag and AgPd electrode pads onto Au- or Cu-plated PCBs.
 - Photovoltaics:
 - Electrically conductive stringing of thin film, organic and crystalline Si solar cells.
 - Compatible with SnCu and AgCu metalized solar ribbons, and TCO substrates such as ITO, ZnO and SnO.
 - Versatility in ribbon bonding geometries, such as dotted or continuous line.
 - In-line/in-situ curing processes in <1 minute at 140°C can be achieved.
 - Reliable green strength holds solar ribbons in position prior to cure.
 - Low temperature cure is well suited for CIGS and OPV/DSC solar cells requiring a low temperature process.
 - Suitable for use on IEC 61646, IEC 61730 and UL 1703 certified solar panels.